NSN 5962-01-307-9932

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View Online at https://aerobasegroup.com/nsn/5962-01-307-9932

Overall Height:

Between 0.357 inches and 0.432 inches

Body Length:

1.490 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

Between 0.172 inches and 0.217 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Electrostatic sensitive and hermetically sealed and burn in and programmable and ultraviolet erasable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

16 input

Case Outline Source And Designator:

D-10 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

